



<b>Session Title:</b>	<b>[WeF3] Nano Thin Film Deposition V</b>
<b>Session Date:</b>	<b>November 13 (Wed.), 2024</b>
<b>Session Time:</b>	<b>16:05-17:45</b>
<b>Session Room:</b>	<b>Room F (Ballroom, 5F, Grand Josun Busan)</b>
<b>Session Chair:</b>	<b>Prof. Taewook Nam (Sejong Univ., Korea)</b>

**[WeF3-1] [Invited]**

**16:05-16:35**

**Interfacial Engineering for Ferroelectric Memories with Improved Performance**

Mihaela Ioana Popovici (imec, Belgium)

**[WeF3-2] [Invited]**

**16:35-17:00**

**Correlation between Device Physics and Material Chemistry in (Hf,Zr)O<sub>2</sub>-Based Ferroelectric Memories**

Min Hyuk Park (Seoul Nat'l Univ., Korea)

**[WeF3-3] [Invited]**

**17:00-17:25**

**Synthesis of Perovskite SrTiO<sub>3</sub> Thin Films by Atomic Layer Deposition for MIM Capacitors**

Woongkyu Lee (Soongsil Univ., Korea)

**[WeF3-4]**

**17:25-17:45**

**Achieving Superior ALD Metal Oxide Films with Organic Molecule Inhibitors**

Seung Hyun Lee, Deok Hyun Kim, Kok Chew Tan, Jung Hun Lim, Young-Soo Park, and Jaesun Jung (Soulbrain Co., Ltd., Korea)